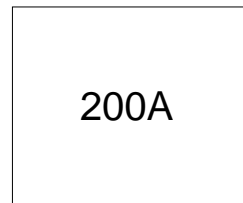


STANDARD RECOVERY DIODES

Stud Version

Features

- Wide current range
- High voltage ratings up to 2400V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC types

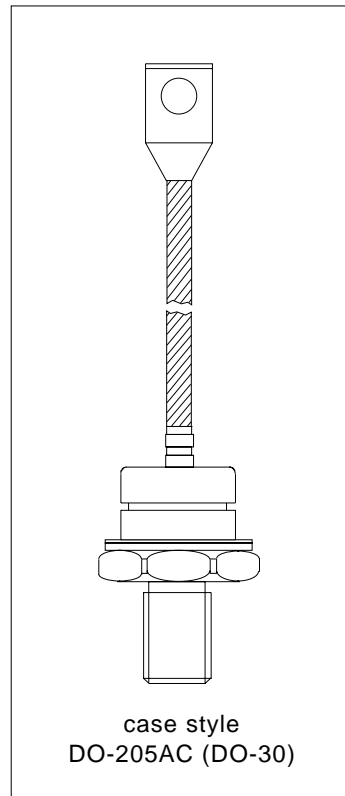


Typical Applications

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

Major Ratings and Characteristics

Parameters	SD200N/R		Units
	1600 to 2000	2400	
$I_{F(AV)}$	200	200	A
@ T_C	110	110	°C
$I_{F(RMS)}$	314	314	A
I_{FSM} @ 50Hz	4700	4700	A
@ 60Hz	4920	4920	A
I^2t @ 50Hz	110	110	KA ² s
@ 60Hz	101	101	KA ² s
V_{RRM} range	1600 to 2000	2400	V
T_J	- 40 to 180	150	°C



ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ $T_J = T_J$ max. mA
SD200N/R	16	1600	1700	15
	20	2000	2100	
	24	2400	2500	

Forward Conduction

Parameter	SD200N/R	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ Case temperature	200	A	180° conduction, half sine wave
	110	°C	
$I_{F(AV)}$ Max. average forward current @ Case temperature	220	A	180° conduction, half sine wave
	100	°C	
$I_{F(RMS)}$ Max. RMS forward current	314	A	DC @ 95°C case temperature
I_{FSM} Max. peak, one-cycle forward, non-repetitive surge current	4700	A	t = 10ms No voltage reappplied
	4920		t = 8.3ms reappplied
	3950		t = 10ms 100% V_{RRM} reappplied
	4140		t = 8.3ms reappplied
I^2t Maximum I^2t for fusing	110	KA ² s	t = 10ms No voltage reappplied
	101		t = 8.3ms reappplied
	78		t = 10ms 100% V_{RRM} reappplied
	71		t = 8.3ms reappplied
I^2/t Maximum I^2/t for fusing	1100	KA ² /s	t = 0.1 to 10ms, no voltage reappplied
$V_{F(TO)1}$ Low level value of threshold voltage	0.90	V	(16.7% x π x $I_{F(AV)}$) < I < π x $I_{F(AV)}$, $T_J = T_J$ max.
$V_{F(TO)2}$ High level value of threshold voltage	1.00		(I > π x $I_{F(AV)}$), $T_J = T_J$ max.
r_{f1} Low level value of forward slope resistance	0.79	m Ω	(16.7% x π x $I_{F(AV)}$) < I < π x $I_{F(AV)}$, $T_J = T_J$ max.
r_{f2} High level value of forward slope resistance	0.64		(I > π x $I_{F(AV)}$), $T_J = T_J$ max.
V_{FM} Max. forward voltage drop	1.40	V	$I_{pk} = 630A$, $T_J = T_J$ max, $t_p = 10ms$ sinusoidal wave

Thermal and Mechanical Specifications

Parameter	SD200N/R		Units	Conditions
	1600to 2000	2400		
T _J Max. junction operating temperature range	-40 to 180	-40 to 150	°C	
T _{stg} Max. storage temperature range	-55 to 200			
R _{thJC} Max. thermal resistance, junction to case	0.23		K/W	DC operation
R _{thCS} Max. thermal resistance, case to heatsink	0.08			Mounting surface, smooth, flat and greased
T Max. allowed mounting torque ±10%	14		Nm	Not lubricated threads
wt Approximate weight	120		g	
Case style	DO-205AC(DO-30)		See Outline Table	

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.041	0.030	K/W	T _J = T _J max.
120°	0.049	0.051		
90°	0.063	0.068		
60°	0.093	0.096		
30°	0.156	0.157		

Ordering Information Table

Device Code

SD	20	0	N	24	P	C
①	②	③	④	⑤	⑥	⑦

- 1** - Diode
- 2** - Essential part number
- 3** - 0 = Standard recovery
- 4** - N = Stud Normal Polarity (Cathode to Stud)
R = Stud Reverse Polarity (Anode to Stud)
- 5** - Voltage code: Code x 100 = V_{RRM} (See Voltage Ratings table)
- 6** - P = Stud base DO-205AC (DO-30) 1/2" 20UNF-2A
- 7** - C = Ceramic Housing

For Metric Device M12 x 1.75 Contact Factory

SD200N/R Series

Bulletin I2080 rev. D 03/03

Outline Table

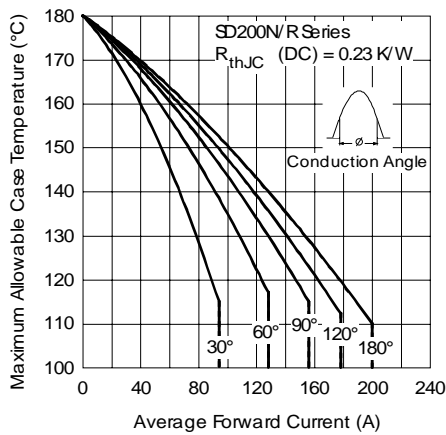
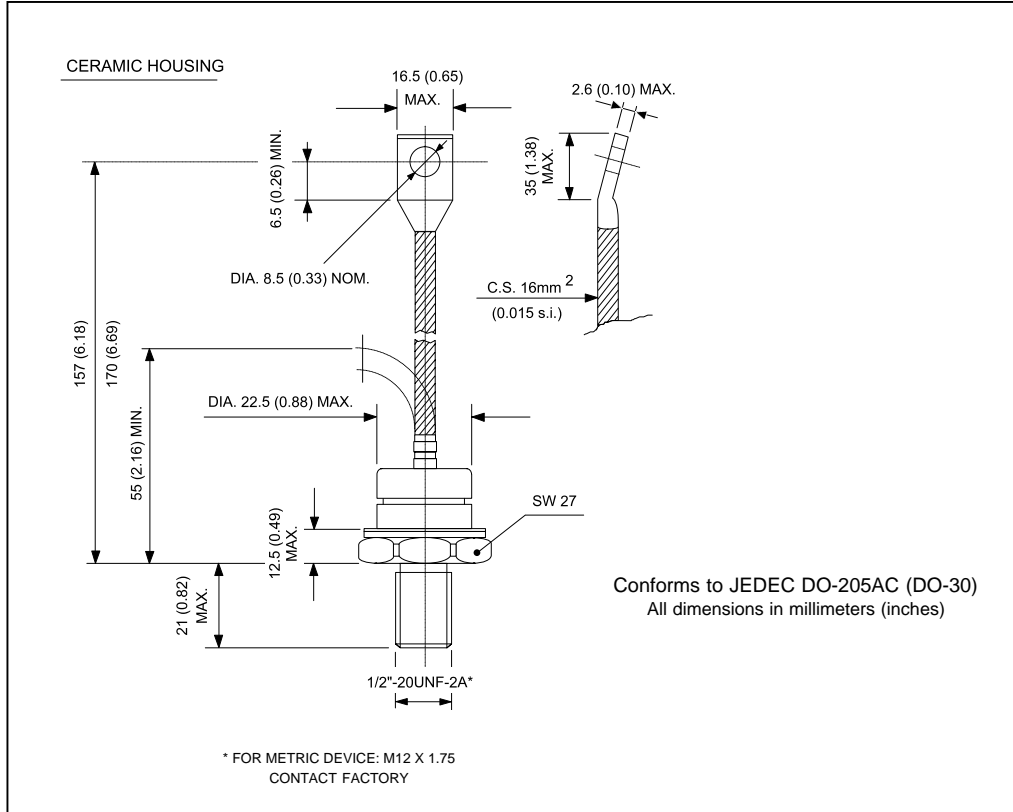


Fig. 1 - Current Ratings Characteristics

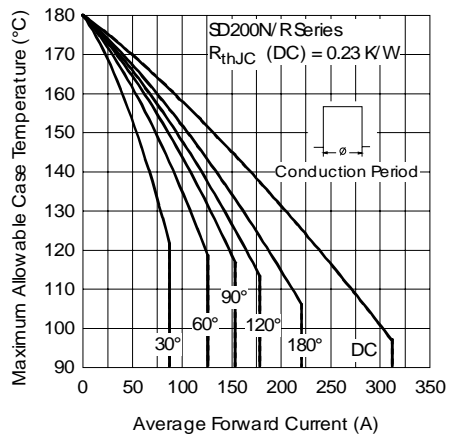


Fig. 2 - Current Ratings Characteristics

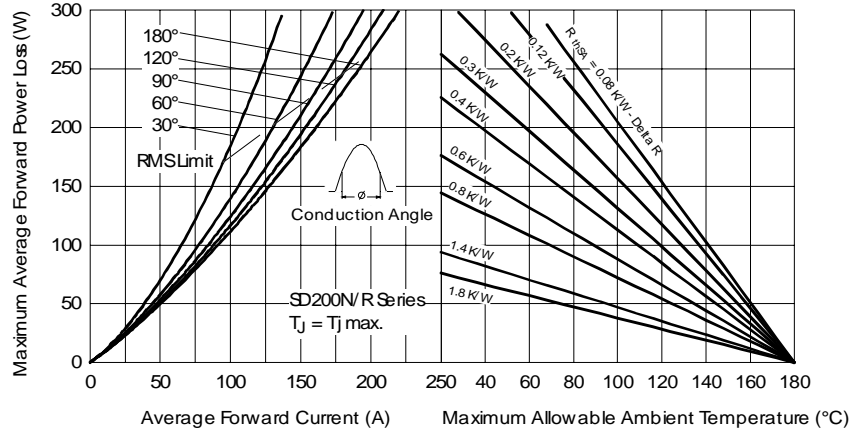


Fig. 3 - Forward Power Loss Characteristics

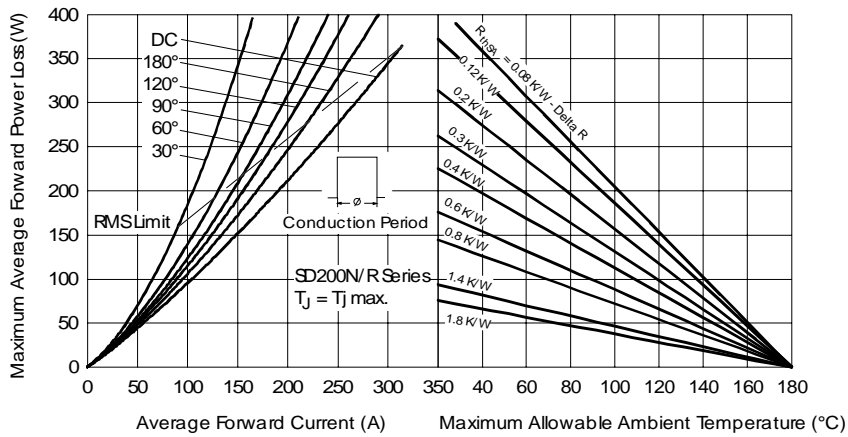


Fig. 4 - Forward Power Loss Characteristics

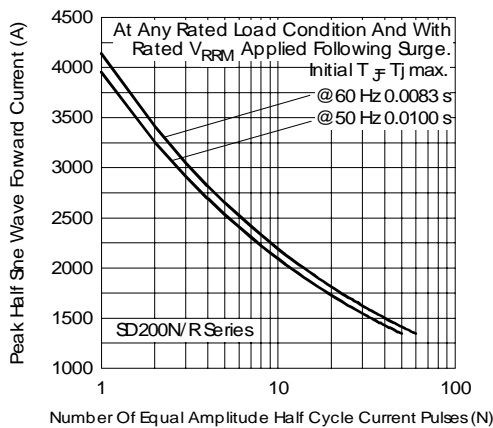


Fig. 5 - Maximum Non-Repetitive Surge Current

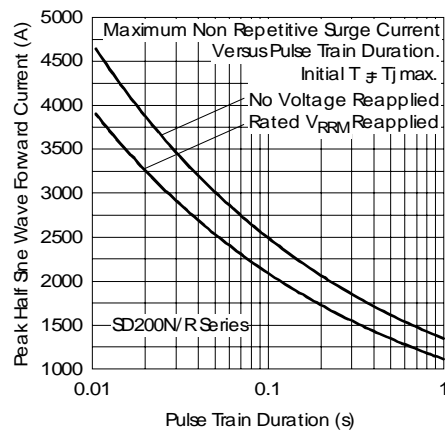


Fig. 6 - Maximum Non-Repetitive Surge Current

SD200N/R Series

Bulletin I2080 rev. D 03/03

International
IR Rectifier

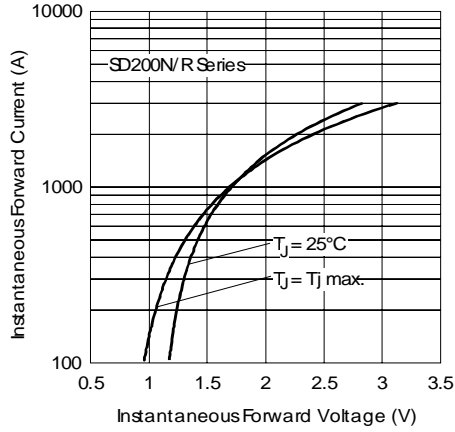


Fig. 7 - Forward Voltage Drop Characteristics

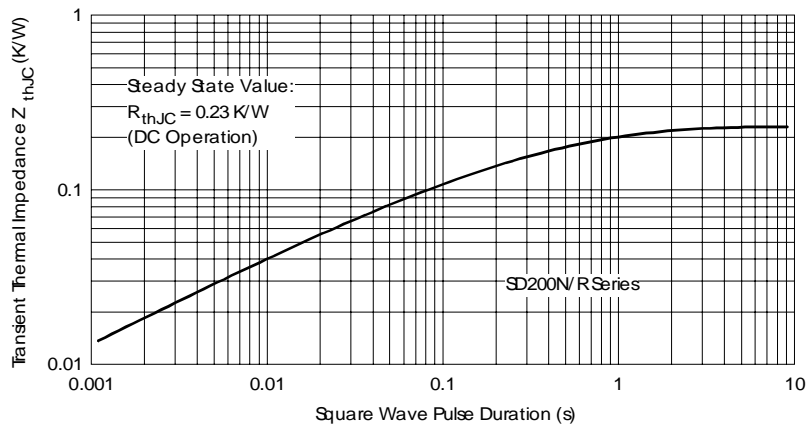


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

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